SEMTECH

## POWER MANAGEMENT

## Description

The SC4503 is a 1.3 MHz current-mode step-up switching regulator with an integrated 1.4A power transistor. Its high switching frequency allows the use of tiny sur-face-mount external passive components. The SC4503 features a combined shutdown and soft-start pin. The optional soft-start function eliminates high input current and output overshoot during start-up. The internal compensation network accommodates a wide range of voltage conversion ratios. The internal switch is rated at 34 V making the device suitable for high voltage applications such as Boost and SEPIC.

The SC4503 is available in low-profile 5-lead TSOT-23 and 8 -lead $2 \times 2 \mathrm{~mm}$ MLPD-W packages. The SC4503's low shutdown current ( $<1 \mu \mathrm{~A}$ ), high frequency operation and small size make it suitable for portable applications.

## Features

Low Saturation Voltage Switch: 260 mV at 1.4A

- 1.3MHz Constant Switching Frequency
- Peak Current-mode Control
- Internal Compensation
- Programmable Soft-Start
- Input Voltage Range From 2.5V to 20V
- Output Voltage up to 27 V
- Uses Small Inductors and Ceramic Capacitors
- Low Shutdown Current (<1 $\mu \mathrm{A}$ )
- Low Profile 5-Lead TSOT-23 and 8-Lead 2X2mm MLPD-W packages
- Fully WEEE and RohS compliant


## Applications

- Local DC-DC Converters
- TFT Bias Supplies
- XDSL Power Supplies
- Medical Equipment
- Digital Cameras
- Portable Devices
- White LED Drivers


## Typical Application Circuit



C1: Murata GRM188R61A105K
C2: Murata GRM21BR61C475K
L1: Sumida CDC5D23B-4R7


Figure 1(a). 5 V to 12 V Boost Converter
Figure 1(b). Efficiency of the 5 V to 12 V Boost Converter

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## Absolute Maximum Ratings

Exceeding the specifications below may result in permanent damage to the device or device malfunction. Operation outside of the parameters specified in the Electrical Characteristics section is not recommended.

| Parameter | Symbol | Maximum | Units |
| :---: | :---: | :---: | :---: |
| Supply Voltage | $\mathrm{V}_{\text {IN }}$ | -0.3 to 20 | V |
| SW Voltage | $\mathrm{V}_{\text {sw }}$ | -0.3 to 34 |  |
| FB Voltages | $V_{\text {FB }}$ | -0.3 to $\mathrm{V}_{\text {IN }}+0.3$ |  |
| SHDN/SS Voltage | $\mathrm{V}_{\text {SHON }}$ | -0.3 to $\mathrm{V}_{\text {IN }}+1$ |  |
| Thermal Resistance Junction to Ambient (TSOT - 23) | $\theta_{\text {JA }}$ | 191* | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance Junction to Ambient (2X2 mm MLPD-W) | $\theta_{\text {JA }}$ | 78* | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Maximum Junction Temperature | $\mathrm{T}_{J}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stG }}$ | -65 to +150 |  |
| Lead Temperature (Soldering)10 sec (TSOT-23) | $\mathrm{T}_{\text {LEAD }}$ | 260 |  |
| Peak IR Reflow Temperature (2X2mm MLPD-W) | $\mathrm{T}_{\text {IR }}$ | 260 |  |
| ESD Rating (Human Body Model) | ESD | 2000 | V |

*Calculated from package in still air, mounted to 3 " x 4.5", 4 layer FR4 PCB with thermal vias under the exposed pad as per JESD51 standards.

## Electrical Characteristics

Unless specified: $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\overline{\mathrm{SHDN} / \mathrm{Ss}}}=3 \mathrm{~V},-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{J}}<85^{\circ} \mathrm{C}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Under-Voltage Lockout Threshold |  |  | 2.2 | 2.5 | V |
| Maximum Operating Voltage |  |  |  | 20 |  |
| Feedback Voltage |  | 1.225 | 1.250 | 1.275 |  |
| Feedback Line Voltage Regulation | $2.5 \mathrm{~V}<\mathrm{V}_{\text {IN }}<20 \mathrm{~V}$ |  | 0.02 |  | \%/V |
| FB Pin Bias Current |  |  | -25 | -50 | nA |
| Switching Frequency |  | 1.15 | 1.30 | 1.55 | MHz |
| Minimum Duty Cycle |  |  |  | 0 | \% |
| Maximum Duty Cycle |  | 86 | 90 |  |  |
| Switch Current Limit |  | 1.4 | 1.9 | 2.5 | A |
| Switch Saturation Voltage | $\mathrm{I}_{\mathrm{sw}}=1.4 \mathrm{~A}$ |  | 260 | 430 | mV |
| Switch Leakage Current | $\mathrm{V}_{\text {sw }}=5 \mathrm{~V}$ |  | 0.01 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {IN }}$ Quiescent Supply Current | $\mathrm{V}_{\overline{S H D N / S S}}=2 \mathrm{~V}, \mathrm{~V}_{\text {FB }}=1.5 \mathrm{~V}$ (not switching) |  | 0.8 | 1.1 | mA |
| $\mathrm{V}_{\text {IN }}$ Supply Current in Shutdown | $\mathrm{V}_{\overline{\text { SHON/SS }}}=0$ |  | 0.01 | 1 | $\mu \mathrm{A}$ |

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Electrical Characteristics (Cont.)
Unless specified: $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\overline{\text { SHDN/SS }}}=3 \mathrm{~V},-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{J}}<85^{\circ} \mathrm{C}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{\text { SHDN/SS Switching Threshold }}$ | $\mathrm{V}_{\mathrm{FB}}=0 \mathrm{~V}$ |  | 1.4 |  | V |
| Shutdown Input High Voltage |  | 2 |  |  | V |
| Shutdown Input Low Voltage |  |  |  | 0.4 |  |
| SHDN/SS Pin Bias Current | $\mathrm{V}_{\overline{\text { SHON/SS }}}=2 \mathrm{~V}$ |  | 22 | 50 | $\mu \mathrm{A}$ |
|  | $\mathrm{V}_{\overline{\text { SHDN } / \text { S }}}=1.8 \mathrm{~V}$ |  | 20 | 45 |  |
|  | $V_{\overline{\text { SHON/Ss }}}=0 \mathrm{~V}$ |  |  | 0.1 |  |
| Thermal Shutdown Temperature |  |  | 155 |  | ${ }^{\circ} \mathrm{C}$ |
| Thermal Shutdown Hysteresis |  |  | 10 |  |  |

Pin Configuration - TSOT - 23


5-LEAD TSOT-23

Ordering Information

| Device $^{(1,2)}$ | Top Mark | Package |
| :---: | :---: | :---: |
| SC4503TSKTRT | BH00 | TSOT-23 |
| SC4503EVB | Evaluation Board |  |

Notes:
(1) Available in tape and reel only. A reel contains 3,000 devices.
(2) Available in lead-free package only. Device is WEEE and RoHS compliant.

Pin Descriptions - TSOT -23

| Pin | Pin Name | Pin Functions |
| :---: | :---: | :--- |
| 1 | SW | Collector of the internal power transistor. Connect to the boost inductor and the freewheeling <br> diode. The maximum switching voltage spike at this pin should be limited to 34V. |
| 2 | GND | Ground. Tie to ground plane. |

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Pin Configuration - $2 \mathrm{~mm} \times 2 \mathrm{~mm}$ MLPD


## 8-LEAD 2X2mm MLPD-W

## Ordering Information

| Device ${ }^{(1,2)}$ | Top Mark | Package |
| :---: | :---: | :---: |
| SC4503WLTRT | E00 | $2 m m X 2 m m$ <br> MLPD-W |
| SC4503_MLPD EVB | Evaluation Board |  |

Notes:
(1) Available in tape and reel only. A reel contains 3,000 devices.
(2) Available in lead-free package only. Device is WEEE and RoHS compliant.

Pin Descriptions - 2X2mm MLPD-W

| Pin | Pin Name | Pin Functions |
| :---: | :---: | :--- |
| 1,2 | SW | Collector of the internal power transistor. Connect to the boost inductor and the free- <br> wheeling diode. The maximum switching voltage spike at this pin should be limited to <br> 34 V. |
| 3 | IN | Power Supply Pin. Bypassed with capacitor close to the pin. |
| 4 | $\overline{\text { SHDN/SS }}$ | Shutdown and Soft-start Pin. Pulling this pin below 0.4 shuts down the converter. Apply- <br> ing more than 2V at this pin enables the SC4503. An external resistor and an external <br> capacitor connected to this pin soft-start the switching regulator. The SC4503 will try <br> to pull the SHDN/SS pin below its 1.4V switching threshold regardless of the external <br> circuit attached to the pin if VIN is below the under-voltage lockout threshold. Tie this pin <br> through an optional resistor to IN or to the output of a controlling logic gate if soft-start is <br> not used. See Applications Information for more details. |
| 5 | FB | The inverting input of the error amplifier. Tie to an external resistive divider to set the <br> output voltage. |
| 6,7 | GND | Ground. Tie to ground plane. |
| 8 | N.C. | No Connection. |
| EDP |  | Solder to the ground plane of the PCB. |

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## Block Diagram



Figure 2. SC4503 Block Diagram

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## Typical Characteristics

FB Voltage vs Temperature

$\mathrm{V}_{\text {IN }}$ Under-voltage Lockout Threshold vs Temperature
 vs Switch Current



Switch Current Limit vs Temperature

$\mathrm{V}_{\text {IN }}$ Quiescent Current vs Temperature


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## Typical Characteristics (Cont.)






Shutdown Pin Thresholds vs Temperature


Switch Current Limit vs Shutdown Pin Voltage


## POWER MANAGEMENT

## Applications Information

## Operation

The SC4503 is a 1.3 MHz peak current-mode step-up switching regulator with an integrated 1.4 A (minimum) power transistor. Referring to the block diagram, Figure 2, the clock CLK resets the latch and blanks the power transistor $\mathrm{Q}_{3}$ conduction. $\mathrm{Q}_{3}$ is switched on at the trailing edge of the clock.

Switch current is sensed with an integrated sense resistor. The sensed current is summed with the slope-compensating ramp and fed into the modulating ramp input of the PWM comparator. The latch is set and $\mathrm{Q}_{3}$ conduction is terminated when the modulating ramp intersects the error amplifier (EA) output. If the switch current exceeds 1.9A (the typical current-limit), then the current-limit comparator ILIM will set the latch and turn off $Q_{3}$. Due to separate pulsewidth modulating and current limiting paths, cycle-by-cycle current limiting is not affected by slope compensation.

The current-mode switching regulator is a dual-loop feedback control system. In the inner current loop the EA output controls the peak inductor current. In the outer loop, the error amplifier regulates the output voltage. The double reactive poles of the output LC filter are reduced to a single real pole by the inner current loop, allowing the internal loop compensation network to accommodate a wide range of input and output voltages.

Applying 0.9V at the SHDNSS pin enables the voltage reference. The signal "REF NOT READY" does not go low until $\mathrm{V}_{\text {IN }}$ exceeds its under-voltage lockout threshold (typically 2.2 V ). Assume that an external resistor is placed between the IN and the SHDNSS pins during startup. The voltage reference is enabled when the SHDNSS voltage rises to 0.9 V . Before $\mathrm{V}_{\text {IN }}$ reaches 2.2 V , "REF NOT READY" is high. $Q_{2}$ turns on and the Zener diode $Z_{1}$ loosely regulates the SHDNSS voltage to 1V (above the reference enabling voltage). The optional external resistor limits the current drawn during under-voltage lockout.

When $\mathrm{V}_{\text {IN }}$ exceeds 2.2 V , "REF NOT READY" goes low. $\mathrm{Q}_{2}$ turns off, releasing SHDNSS. If an external capacitor is connected from the SHDNSS pin to the ground, the SHDNSS voltage will ramp up slowly. The error amplifier output, which is
clamped by D1 and Q1, follows the voltage at the SHDNSS pin. The input inductor current, which is in turn controlled by the error amplifier output, also ramps up gradually. Soft-starting the SC4503 in this manner eliminates high input current and output overshoot. Under fault condition ( $\mathrm{V}_{\text {IN }}<2.2 \mathrm{~V}$ or over-temperature), the soft-start capacitor is discharged to 1 V . When the fault condition disappears, the converter again undergoes soft-start.

## Setting the Output Voltage

An external resistive divider $R_{1}$ and $R_{2}$ with its center tap tied to the FB pin (Figure 3) sets the output voltage.

$$
\begin{equation*}
R_{1}=R_{2}\left(\frac{V_{\text {OUT }}}{1.25 V}-1\right) \tag{1}
\end{equation*}
$$



Figure 3. $R_{1}-R_{2}$ Divider Sets the Output Voltage

The input bias current of the error amplifier will introduce an error of:

$$
\begin{equation*}
\frac{\Delta \mathrm{V}_{\text {OUT }}}{\mathrm{V}_{\text {OUT }}}=-\frac{25 \mathrm{nA} \cdot\left(\mathrm{R}_{1} \| \mathrm{R}_{2}\right) \cdot 100}{1.25 \mathrm{~V}} \% \tag{2}
\end{equation*}
$$

The percentage error of a $\mathrm{V}_{\text {out }}=5 \mathrm{~V}$ converter with $\mathrm{R}_{1}=$ $100 \mathrm{k} \Omega$ and $R_{2}=301 \mathrm{k} \Omega$ is

$$
\frac{\Delta \mathrm{V}_{\text {OUT }}}{\mathrm{V}_{\text {OUT }}}=-\frac{25 \mathrm{nA} \cdot(100 \mathrm{k} \| 301 \mathrm{k}) \cdot 100}{1.25 \mathrm{~V}}=-0.15 \%
$$

This error is much less than the ratio tolerance resulting from the use of $1 \%$ resistors in the divider string.

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## Applications Information (Cont.)

## Duty Cycle

The duty cycle D of a boost converter in continuous-conduction mode (CCM) is:

$$
\begin{equation*}
\mathrm{D}=\frac{1-\frac{V_{\text {IN }}}{\mathrm{V}_{\text {OUT }}+V_{D}}}{1-\frac{V_{\text {CESAT }}}{V_{\text {OUT }}+V_{D}}} \tag{3}
\end{equation*}
$$

where $\mathrm{V}_{\text {CESAT }}$ is the switch saturation voltage and $\mathrm{V}_{\mathrm{D}}$ is voltage drop across the rectifying diode.

## Maximum Output Current

In a boost switching regulator the inductor is connected to the input. The inductor DC current is the input current. When the power switch is turned on, the inductor current flows into the switch. When the power switch is off, the inductor current flows through the rectifying diode to the output. The output current is the average diode current. The diode current waveform is trapezoidal with pulse width (1-D)T (see Figure 4). The output current available from


Figure 4. Current Waveforms in a Boost Converter
a boost converter therefore depends on the converter operating duty cycle. The power switch current in the SC4503 is internally limited to at least 1.4A. This is also the maximum peak inductor or the peak input current. By estimating the conduction losses in both the switch and the diode, an expression of the maximum available output current of a boost converter can be derived:

$$
\begin{equation*}
\mathrm{I}_{\text {OUTMAX }}=\frac{\mathrm{I}_{\text {LIM }} \mathrm{V}_{\text {IN }}}{\mathrm{V}_{\text {OUT }}}\left[1-\frac{\mathrm{D}}{65}-\frac{\mathrm{V}_{\mathrm{D}}-\mathrm{D}\left(\mathrm{~V}_{\mathrm{D}}-\mathrm{V}_{\text {CESAT }}\right)}{\mathrm{V}_{\text {IN }}}\right] \tag{4}
\end{equation*}
$$

where $I_{\text {LIM }}$ is the switch current limit.
It is worth noting that $I_{\text {outmax }}$ is directly proportional to the ratio $\frac{V_{\text {IN }}}{V_{\text {OUT }}}$ and that switching losses are neglected in its derivation. Equation (4) therefore over-estimates the maximum output current, however it is a useful first-order approximation.

Using $\mathrm{V}_{\text {CESAT }}=0.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=0.5 \mathrm{~V}$ and $\mathrm{I}_{\text {LIM }}=1.4 \mathrm{~A}$ in (3) and (4), the maximum output current for three $\mathrm{V}_{\text {iv }}$ and $\mathrm{V}_{\text {out }}$ combinations are tabulated (Table 1).

| $\mathrm{V}_{\text {IN }}(\mathrm{V})$ | $\mathrm{V}_{\text {OUT }}(\mathrm{V})$ | D | $\mathrm{I}_{\text {OUT }}(\mathrm{A})$ |
| :---: | :---: | :---: | :---: |
| 3.3 | 12 | 0.754 | 0.34 |
| 3.3 | 5 | 0.423 | 0.80 |
| 5 | 12 | 0.615 | 0.53 |

Table 1. Calculated Maximum Output Currents

## Maximum Duty-Cycle Limitation

The power transistor in the SC4503 is turned off every switching period for 80 ns . This minimum off time limits the maximum duty cycle of the regulator. A boost converter with high $\frac{V_{\text {OUT }}}{V_{\text {IN }}}$ ratio requires long switch on time and high duty cycle. If the required duty cycle is higher than the attainable maximum, then the converter will operate in dropout. (Dropout is a condition in which the regulator cannot attain its set output voltage below current limit.)

Note: dropout can occur when operating at low input voltages (<3V) and with off times approaching 100ns. Shorten the PCB trace between the power source and the device input pin, as line drop may be a significant percentage of the input voltage. A regulator in dropout may appear as if it is in current limit. The cycle-by-cycle current limit of the SC4503 is duty-cycle and input voltage invariant and should be at least 1.4 A . If the converter output is below its set value and switch current limit is not reached (1.4A), then the converter is likely in dropout.

Example: Determine the highest attainable output voltage when boosting from a single Li-ion cell.

Equation (3) can be re-arranged as:

## POWER MANAGEMENT

## Applications Information (Cont.)

$$
\begin{equation*}
V_{\text {OUT }}=\frac{V_{\text {IN }}-D V_{\text {CESAT }}}{1-D}-V_{D} \tag{5}
\end{equation*}
$$

Assuming that the voltage of a nearly discharged Li-ion cell is 2.6 V . Using $\mathrm{V}_{\mathrm{D}}=0.5 \mathrm{~V}, \mathrm{~V}_{\text {CESAT }}=0.3 \mathrm{~V}$ and $\mathrm{D}=0.86$ in (5),

$$
\mathrm{V}_{\text {OUT }}<\frac{2.6-0.86 \cdot 0.3}{1-0.86}-0.5=16 \mathrm{~V}
$$

Transient headroom requirement further reduces the maximum achievable output voltage to below 16 V .

## Minimum Controllable On-Time

The operating duty cycle of a boost converter decreases as $\mathrm{V}_{\mathrm{IN}}$ approaches $\mathrm{V}_{\text {out }}$ Sensed switch current ramp modulates the pulse width in a current-mode switching regulator. This current ramp is absent unless the switch is turned on. The intersection of this ramp with the error amplifier output determines the switch on-time. The propagation delay time required to immediately turn off the switch after it is turned on is the minimum controllable on time. Measured minimum on time of the SC4503 is load-dependent and ranges from 180 ns to 220 ns at room temperature. The switch in the SC4503 is either not turned on, or, for at least this minimum. If the regulator requires a switch on-time less than this controllable minimum, then it will either skip cycles or start to jitter.

## Inductor Selection

The inductor ripple current $\Delta I_{\llcorner }$of a boost converter in con-tinuous-conduction mode is

$$
\begin{equation*}
\Delta \mathrm{I}_{\mathrm{L}}=\frac{\mathrm{D}\left(\mathrm{~V}_{\text {IN }}-\mathrm{V}_{\text {CESAT }}\right)}{\mathrm{fL}} \tag{6}
\end{equation*}
$$

where $f$ is the switching frequency and $L$ is the inductance.

Substituting (3) into (6) and neglecting $\mathrm{V}_{\text {CESAT }}$

$$
\begin{equation*}
\Delta \mathrm{I}_{\mathrm{L}}=\frac{\mathrm{V}_{\text {IN }}}{\mathrm{fL}}\left(1-\frac{\mathrm{V}_{\text {IN }}}{\mathrm{V}_{\text {OUT }}+\mathrm{V}_{\mathrm{D}}}\right) \tag{7}
\end{equation*}
$$

In current-mode control, the slope of the modulating (sensed switch current) ramp should be steep enough to
lessen jittery tendency but not so steep that large flux swing decreases efficiency. For continuous-conduction mode operation, inductor ripple current $\Delta I_{L}$ between 0.35 A and 0.6 A is a good compromise. Setting $\Delta \mathrm{I}_{\mathrm{L}}=0.43 \mathrm{~A}, \mathrm{~V}_{\mathrm{D}}=0.5 \mathrm{~V}$ and $f=1.3 \mathrm{MHz}$ in (7),

$$
\begin{equation*}
L=\frac{V_{I N}}{f \Delta I_{L}}\left(1-\frac{V_{I N}}{V_{\text {OUT }}+V_{D}}\right)=\frac{V_{I N}}{0.56}\left(1-\frac{V_{I N}}{V_{\text {OUT }}+0.5}\right) \tag{8}
\end{equation*}
$$

where L is in $\mu \mathrm{H}$.
Equation (7) shows that for a given $\mathrm{V}_{\text {out }}, \Delta \mathrm{I}_{\mathrm{L}}$ is the highest when $\mathrm{V}_{\text {IN }}=\frac{\left(\mathrm{V}_{\text {OUT }}+\mathrm{V}_{\mathrm{D}}\right)}{2}$. If $\mathrm{V}_{\text {IN }}$ varies over a wide range, then choose L based on the nominal input voltage.

The saturation current of the inductor should be 20-30\% higher than the peak current limit (1.9 A). Low-cost powder iron cores are not suitable for high-frequency switching power supplies due to their high core losses. Inductors with ferrite cores should be used.

## Discontinuous-Conduction Mode

The output-to-input voltage conversion ratio $M=\frac{V_{\text {OUT }}}{V_{\text {IN }}}$ in continuous-conduction mode is limited by the maximum duty cycle $\mathrm{D}_{\text {Max }}$ :

$$
\mathrm{M}<\frac{1}{1-\mathrm{D}_{\mathrm{MAX}}}=\frac{1}{1-0.86}=7.1
$$

Higher voltage conversion ratios can be achieved by operating the boost converter in full-time discontinuous-conduction mode (DCM). Define $R=\frac{V_{\text {OUT }}}{I_{\text {OUT }}}$ as the equivalent output load resistance. The following inequalities must be satisfied for DCM operation:

$$
\begin{equation*}
\frac{\mathrm{Lf}}{\mathrm{R}}<\frac{\mathrm{M}-1}{2 \mathrm{M}^{3}} \tag{9}
\end{equation*}
$$

and,

$$
\begin{equation*}
I_{\text {OUT }}=\frac{V_{\text {OUT }}}{R}<\frac{0.7 \mathrm{~A}}{\mathrm{M}} \tag{10}
\end{equation*}
$$

## POWER MANAGEMENT

## Applications Information (Cont.)

Switch on duty ratio in DCM is given by,

$$
\begin{equation*}
D=\sqrt{\frac{2 L f}{R} M(M-1)} \tag{11}
\end{equation*}
$$

Higher input current ripples and lower output current are the drawbacks of DCM operation.

## Input Capacitor

The input current in a boost converter is the inductor current, which is continuous with low RMS current ripples. A 2.2-4.7 $\mu \mathrm{F}$ ceramic input capacitor is adequate for most applications.

## Output Capacitor

Both ceramic and low ESR tantalum capacitors can be used as output filtering capacitors. Multi-layer ceramic capacitors, due to their extremely low ESR ( $<5 \mathrm{~m} \Omega$ ), are the best choice. Use ceramic capacitors with stable temperature and voltage characteristics. One may be tempted to use Z 5 U and Y 5 V ceramic capacitors for output filtering because of their high capacitance density and small sizes. However these types of capacitors have high temperature and high voltage coefficients. For example, the capacitance of a $\mathrm{Z5U}$ capacitor can drop below $60 \%$ of its room temperature value at $-25^{\circ} \mathrm{C}$ and $90^{\circ} \mathrm{C}$. X 5 R ceramic capacitors, which have stable temperature and voltage coefficients, are the preferred type.

The diode current waveform in Figure 4 is discontinuous with high ripple-content. Unlike a buck converter in which the inductor ripple current $\Delta \mathrm{I}_{\mathrm{L}}$ determines the output ripple voltage. The output ripple voltage of a boost regulator is much higher and is determined by the absolute inductor current. Decreasing the inductor ripple current does not reduce the output ripple voltage appreciably. The current flowing in the output filter capacitor is the difference between the diode current and the output current. This capacitor current has a RMS value of:

$$
\begin{equation*}
\mathrm{I}_{\text {out }} \sqrt{\frac{v_{\text {out }}}{\mathrm{V}_{\text {IN }}}-1} \tag{12}
\end{equation*}
$$

If a tantalum capacitor is used, then its ripple current rating in addition to its ESR will need to be considered.

When the switch is turned on, the output capacitor supplies the load current $\mathrm{I}_{\text {out }}$ (Figure 4). The output ripple voltage due to charging and discharging of the output capacitor is therefore:

$$
\begin{equation*}
\Delta \mathrm{V}_{\text {OUT }}=\frac{\mathrm{I}_{\text {OUT }} \mathrm{DT}}{\mathrm{C}_{\text {OUT }}} \tag{13}
\end{equation*}
$$

For most applications, a $10-22 \mu \mathrm{~F}$ ceramic capacitor is sufficient for output filtering. It is worth noting that the output ripple voltage due to discharging of a $10 \mu \mathrm{~F}$ ceramic capacitor (13) is higher than that due to its ESR.

## Rectifying Diode

For high efficiency, Schottky barrier diodes should be used as rectifying diodes for the SC4503. These diodes should have an average forward current rating at least equal to the output current and a reverse blocking voltage of at least a few volts higher than the output voltage. For switching regulators operating at low duty cycles (i.e. low output voltage to input voltage conversion ratios), it is beneficial to use rectifying diodes with somewhat higher average current ratings (thus lower forward voltages). This is because the diode conduction interval is much longer than that of the transistor. Converter efficiency will be improved if the voltage drop across the diode is lower.

The rectifying diodes should be placed close to the SW pin of the SC4503 to minimize ringing due to trace inductance. Surface-mount equivalents of 1N5817 and 1N5818, MBRM120, MBR0520L, ZHCS400, 10BQ015 and equivalent are suitable.

## Shutdown and Soft-Start

The shutdown (SHDNSS) pin is a dual function pin. When driven from a logic gate with $\mathrm{V}_{\mathrm{OH}}>2 \mathrm{~V}$, the SHDNSS pin functions as an on/off input to the SC4503. When the shutdown pin is below 2 V , it clamps the error amplifier output to $\mathrm{V}_{\overline{\mathrm{SHDN}} / \mathrm{Ss}}$ and reduces the switch current limit. Connecting $\mathrm{R}_{\mathrm{ss}}$ and $\mathrm{C}_{\mathrm{ss}}$ to the SHDNSS pin (Figure 5) slows the voltage rise at the pin during start-up. This forces the peak inductor current (hence the input current) to follow a slow ramp, thus achieving soft-start.

## POWER MANAGEMENT

## Applications Information (Cont.)

The minimum SHDN SS voltage for switching is 1.4 V . The graph "Switch Current Limit vs. Shutdown Pin Voltage" in the "Typical Characteristics" shows that the SHDN SS pin voltage needs to be at least 2V for the SC4503 to deliver its rated power. The effect of the SHDN SS voltage on the SC4503 is analog between 1.4 V and 2 V . Within this range the switch current limit is determined not by ILIM but instead by the PWM signal path (see Figure 2). Moreover it varies with duty cycle and the shutdown pin voltage.

Pulling the SHDN SS pin below 0.4 V shuts down the SC4503, drawing less than $1 \mu \mathrm{~A}$ from the input power supply. For voltages above 2 V and below 0.4 V , the SHDN $S$ p pin can be regarded as a digital on/off input. Figure 5 shows several ways of interfacing the control logic to the shutdown pin. In Figure 5(a) soft-start is not used and the logic gate drives the shutdown pin through a small ( $\approx 1 \mathrm{k} \Omega$ ) optional resistor $R_{s S} . R_{s S}$ limits the current drawn by the SC4503 internal

(b)

(d)

(f)

Figure 5. Methods of Driving the Shutdown Pin and Soft-starting the SC4503
(a) Directly Driven from a Logic Gate. $\mathrm{R}_{\text {LIм }}$ Limits the Gate Output Current during Fault,
(b) Soft-start Only,
(c) Driven from a Logic Gate with Soft-start,
(d) Driven from a Logic Gate with Soft-start (1.7V < $\mathrm{V}_{\text {OH }}<2 \mathrm{~V}$ ),
(e) Driven from an Open-collector NPN Transistor with Soft-start and
(f) Driven from a Logic Gate (whose $\mathrm{V}_{\mathrm{OH}}>\mathrm{V}_{\mathrm{IN}}$ ) with Soft-start.

## POWER MANAGEMENT

## Applications Information (Cont.)

circuit from the driving logic gate during fault condition. In Figure 5(f) the shutdown pin is driven from a logic gate whose $\mathrm{V}_{\text {он }}$ is higher than the supply voltage to the SC4503. The diode clamps the maximum shutdown pin voltage to one diode voltage above the input power supply.

During soft-start, $\mathrm{C}_{\text {ss }}$ is charged by the difference between the $\mathrm{R}_{\mathrm{sS}}$ current and the shutdown pin current, $I_{\text {SHDN } / \mathrm{Ss}}$. In steady state, the voltage drop across $\mathrm{R}_{\mathrm{ss}}$ reduces the shutdown pin voltage according to the following equation:

$$
\begin{equation*}
V_{\text {SHDN } / \mathrm{Ss}}=V_{E N}-R_{S S} I_{\text {SHDN } / \mathrm{SS}} \tag{14}
\end{equation*}
$$

In order for the SC4503 to achieve its rated switch current, $\mathrm{V}_{\overline{\text { SHDN }} / \mathrm{ss}}$ must be greater than 2 V in steady state. This puts an upper limit on $R_{\text {SS }}$ for a given enable voltage $\mathrm{V}_{\mathrm{EN}}(=$ voltage applied to $R_{S S}$ ). The maximum specified $I_{\text {SHDN } / s s}$ is $50 \mu \mathrm{~A}$ with $\mathrm{V}_{\overline{\mathrm{SHDN}} / \mathrm{ss}}=2 \mathrm{~V}$ (see "Electrical Characteristics"). The largest $\mathrm{R}_{\text {ss }}$ can be found using (14):

$$
\mathrm{R}_{\mathrm{SS}}<\frac{\mathrm{V}_{\mathrm{EN}(\mathrm{MIN})}-2}{50 \mu \mathrm{~A}}
$$

If the enable signal is less than 2 V , then the interfacing options shown in Figures 5(d) and 5(e) will be preferred. The methods shown in Figures 5(a) and 5(c) can still be used however the switch current limit will be reduced. Variations of $I_{\text {SHDN/ }}$ ss and switch current limit with SHDNSS pin voltage and temperature are shown in the "Typical Characteristics". Shutdown pin current decreases as temperature increases. Switch current limit at a given $\mathrm{V}_{\text {SHDN//ss }}$ also decreases as temperature rises. Lower shutdown pin current flowing through $\mathrm{R}_{\mathrm{ss}}$ at high temperature results in higher shutdown pin voltage. However reduction in switch current limit (at a given $\mathrm{V}_{\overline{\mathrm{SHDN} / \mathrm{Ss}}}$ ) at high temperature is the dominant effect.

## Feed-Forward Compensation

Figure 6 shows the equivalent circuit of a boost converter. Important poles and zeros of the overall loop response are:
Low frequency integrator pole, $\omega_{p 1}=-\frac{1}{R_{0} C_{C}}$,

Output filter pole, $\omega_{\mathrm{p} 2}=-\frac{2 \mathrm{I}_{\mathrm{OUT}}}{\mathrm{V}_{\mathrm{OUT}} \mathrm{C}_{2}}=-\frac{2}{\mathrm{RC}_{2}}$,
Compensating zero, $\omega_{z 1}=-\frac{1}{R_{C} C_{C}}$ and
Right half plane (RHP) zero, $\omega_{z 2}=\frac{R(1-D)^{2}}{L}$.

$R_{\mathrm{O}}$ is the equivalent output resistance of the error amplifier

Figure 6. Simplified Equivalent Model of a Boost Converter

The poles $p_{1}, p_{2}$ and the RHP zero $z_{2}$ all increase phase shift in the loop response. For stable operation, the overall loop gain should cross OdB with $-20 \mathrm{~dB} /$ decade slope. Due to the presence of the RHP zero, the OdB crossover frequency should not be more than $\frac{\omega_{z 2}}{3}$. The internal compensating zero $z_{1}$ provides phase boost beyond $p_{2}$. In general the converter is more stable with widely spaced filter pole $p_{2}$ and the RHP zero $z_{2}$. The RHP zero moves to low frequency when either the duty-cycle D or the output current $\mathrm{I}_{\text {out }}$ increases. It is beneficial to use small inductors and larger output capacitors especially when operating at high $\frac{V_{\text {OUT }}}{V_{\text {IN }}}$ ratios.

A feed-forward capacitor $\mathrm{C}_{4}$ is needed for stability. The value of $\mathrm{C}_{4}$ can be determined empirically by observing the inductor current and the output voltage during load transient. Starting with a value between $\frac{1.5 \mu \mathrm{~s}}{\mathrm{R}_{1}}$ and $\frac{6.5 \mu \mathrm{~s}}{\mathrm{R}_{1}}, \mathrm{C}_{4}$ is adjusted until there is no excessive ringing or overshoot in inductor current and output voltage during load transient. Sizing the inductor such that its ripple current is about 0.5A also improves phase margin and transient response.

## POWER MANAGEMENT

## Applications Information (Cont.)

Figures 7(a)-7(c) show the effects of different values of inductance and feed-forward capacitance on transient responses. In a battery-operated system if $\mathrm{C}_{4}$ is optimized for the minimum $\mathrm{V}_{\mathbb{I N}}$ and the maximum load step, the converter will be stable over the entire input voltage range.

(a) $\mathrm{L}_{1}=5.6 \mu \mathrm{H}$ and $\mathrm{C}_{4}=2.2 \mathrm{pF}$

(b) $\mathrm{L}_{1}=5.6 \mu \mathrm{H}$ and $\mathrm{C}_{4}=3.3 \mathrm{pF}$

(c) $\mathrm{L}_{1}=3.3 \mu \mathrm{H}$ and $\mathrm{C}_{4}=2.7 \mathrm{pF}$

Figure 7. Different inductances and feed-forward capacitances affect the load transient responses of the 3.3 V to 12 V step-up converter in Figure 10(a). $I_{\text {out }}$ is switched between 90 mA and 280 mA .

## Board Layout Considerations

In a step-up switching regulator, the output filter capacitor, the main power switch and the rectifying diode carry pulse currents with high di/dt. For jitter-free operation, the size of the loop formed by these components should be minimized. Since the power switch is integrated inside the SC4503, grounding the output filter capacitor next to the SC4503 ground pin minimizes size of the high di/dt current loop. The input bypass capacitors should also be placed close to the input pins. Shortening the trace at the SW node reduces the parasitic trace inductance. This not only reduces EMI but also decreases switching voltage spikes.

Figure 8 shows how various external components are placed around the SC4503.

The large surrounding ground plane acts as a heat sink for the device.


Figure 8. Suggested PCB Layout for the SC4503.

## POWER MANAGEMENT

Typical Application Circuits


L1: Murata LQH32C
C1: Murata GRM219R60J475K
Figure 9. Driving Two 6 White LED Strings from 5 V . Zener diode $\mathrm{D}_{2}$ protects the converter from over-voltage damage when both LED strings become open.

POWER MANAGEMENT
Typical Application Circuits


L1: Coiltronics LD1
C1: Murata GRM188R61A225K
C2: Murata GRM21BR61C475K
Figure 10(a). 3.3 V to 12 V Boost Converter with Soft-start


Figure 10(b). Efficiency vs Load Current


Upper Trace : Output Voltage, AC Coupled, 0.5V/div Lower Trace : Input Inductor Current, 0.5A/div

Figure 10(c). Load Transient Response of the Circuit in Figure 10(a). $\mathrm{I}_{\text {out }}$ is switched between 90 mA and 280 mA

## POWER MANAGEMENT

## Typical Application Circuits



Figure 11(a). Single Li-ion Cell to 5V Boost Converter


Upper Trace : Output Voltage, AC Coupled, 0.2V/div Lower Trace : Inductor Current, 0.5A/div


Upper Trace : Output Voltage, AC Coupled, 0.2V/div Lower Trace : Inductor Current, 0.5A/div

Figure 11(c). Load Transient Response. $\mathrm{I}_{\text {out }}$ is switched between 0.1A and 0.5A

Figure 11(b). Efficiency of the Li-ion Cell to 5 V Boost Converter

Figure 11(d). Load Transient Response. $\mathrm{I}_{\text {out }}$ is switched between 0.15A and 0.9A

POWER MANAGEMENT
Typical Application Circuits


L1 and L2: Coiltronics DRQ73-3R3
C1: Murata GRM188R61A105K
C2: Murata GRM21BR60J106K
C5: Murata GRM188R61A225K
Figure 12(a). Single Li-ion Cell to 3.3V SEPIC Converter.


Figure 12(b). Efficiency vs Load Current


Upper Trace : Output Voltage, AC Coupled, 0.2V/div Lower Trace : Input Inductor Current, 0.2A/div

Figure 12(c). Load Transient Response of the Circuit in Figure 12(a). $I_{\text {out }}$ is switched between 100 mA and 500 mA

## POWER MANAGEMENT

## Typical Application Circuits



D2 - D7 : BAT54S
L1 : Sumida CDC5D23B-4R7M
C2: Murata GRM21BR61C475K
C1: Murata GRM188R61A105K
Figure 13(a). Triple-Output TFT Power Supply with Soft-Start

$400 \mu \mathrm{~s} / \mathrm{div}$
CH1 : OUT1 Voltage, 5V/div
CH2 : OUT2 Voltage, 20V/div
CH3 : OUT3 Voltage, 5V/div
CH4 : RUN Voltage, 5V/div
Figure 13(b). TFT Power Supply Start-up Transient as the RUN Voltage is Stepped from 0 to 3.3 V

$40 \mu \mathrm{~s} / \mathrm{div}$
Upper Trace : Output Voltage, AC Coupled, 0.5V/div Lower Trace : Inductor Current, 0.5A/div

Figure 13(c). Load Transient Response. I ${ }_{\text {out1 }}$ is switched between 50 mA and 350mA

## POWER MANAGEMENT

## EVB Schematic



POWER MANAGEMENT

## Outline Drawing - TSOT-23



detail A

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE - $\mathrm{H}-$
3. DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS
4. REFERENCE JEDEC STD MO-193, VARIATION AB.

## Land Pattern - TSOT-23



| DIMENSIONS |  |  |
| :---: | :---: | :---: |
| DIM | INCHES | MILLIMETERS |
| C | $(.087)$ | $(2.20)$ |
| G | .031 | 0.80 |
| P | .037 | 0.95 |
| X | .024 | 0.60 |
| Y | .055 | 1.40 |
| Z | .141 | 3.60 |

NOTES:

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

POWER MANAGEMENT
Outline Drawing - 8 Lead 2X2mm MLPD-W


NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

Land Pattern - 8 Lead 2X2mm MLPD-W


NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.
3. THERMAL VIAS IN THE LAND PATTERN OF THE EXPOSED PAD SHALL BE CONNECTED TO A SYSTEM GROUND PLANE. FAILURE TO DO SO MAY COMPROMISE THE THERMAL AND/OR FUNCTIONAL PERFORMANCE OF THE DEVICE.

Contact Information

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